

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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## SWITCHING

### N-CHANNEL POWER MOS FET

#### DESCRIPTION

The 2SK3899 is N-channel MOS Field Effect Transistor designed for high current switching applications.

#### ORDERING INFORMATION

| PART NUMBER | PACKAGE          |
|-------------|------------------|
| 2SK3899-ZK  | TO-263 (MP-25ZK) |

#### FEATURES

- Super low on-state resistance

$R_{DS(on)1} = 5.3 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 42 \text{ A)}$

$R_{DS(on)2} = 6.5 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 42 \text{ A)}$

- Low  $C_{iss}$ :  $C_{iss} = 5500 \text{ pF TYP.}$
- Built-in gate protection diode

(TO-263)



#### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

|  |                |             |                  |
|--|----------------|-------------|------------------|
| Drain to Source Voltage ( $V_{GS} = 0 \text{ V}$ )   | $V_{DSS}$      | 60          | V                |
| Gate to Source Voltage ( $V_{DS} = 0 \text{ V}$ )    | $V_{GSS}$      | $\pm 20$    | V                |
| Drain Current (DC) ( $T_C = 25^\circ\text{C}$ )      | $I_{D(DC)}$    | $\pm 84$    | A                |
| Drain Current (pulse) <sup>Note1</sup>               | $I_{D(pulse)}$ | $\pm 336$   | A                |
| Total Power Dissipation ( $T_C = 25^\circ\text{C}$ ) | $P_{T1}$       | 146         | W                |
| Total Power Dissipation ( $T_A = 25^\circ\text{C}$ ) | $P_{T2}$       | 1.5         | W                |
| Channel Temperature                                  | $T_{ch}$       | 150         | $^\circ\text{C}$ |
| Storage Temperature                                  | $T_{stg}$      | -55 to +150 | $^\circ\text{C}$ |
| Single Avalanche Energy <sup>Note2</sup>             | $E_{AS}$       | 245         | mJ               |
| Repetitive Avalanche Current <sup>Note3</sup>        | $I_{AR}$       | 49.5        | A                |
| Repetitive Avalanche Energy <sup>Note3</sup>         | $E_{AR}$       | 245         | mJ               |

**Notes 1.**  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$

**2.** Starting  $T_{ch} = 25^\circ\text{C}$ ,  $V_{DD} = 30 \text{ V}$ ,  $R_G = 25 \Omega$ ,  $V_{GS} = 20 \rightarrow 0 \text{ V}$ ,  $L = 100 \mu\text{H}$

**3.**  $R_G = 25 \Omega$ ,  $T_{ch(peak)} \leq 150^\circ\text{C}$

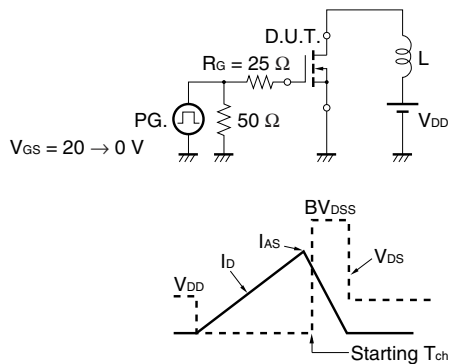
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**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)**

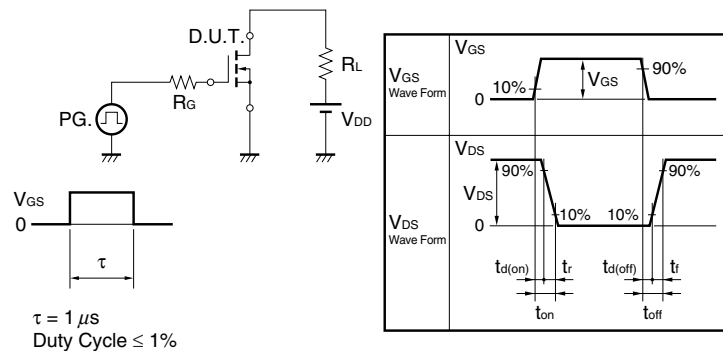
| CHARACTERISTICS                                     | SYMBOL               | TEST CONDITIONS                                | MIN. | TYP. | MAX. | UNIT |
|---|----------------------|--|------|------|------|------|
| Zero Gate Voltage Drain Current                     | I <sub>DSS</sub>     | V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V  |      |      | 10   | μA   |
| Gate Leakage Current                                | I <sub>GSS</sub>     | V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V |      |      | ±10  | μA   |
| Gate Cut-off Voltage                                | V <sub>GS(off)</sub> | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA  | 1.5  | 2.0  | 2.5  | V    |
| Forward Transfer Admittance <sup>Note</sup>         | y <sub>fs</sub>      | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 42 A  | 35   | 70   |      | S    |
| Drain to Source On-state Resistance <sup>Note</sup> | R <sub>DS(on)1</sub> | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 42 A  |      | 4.2  | 5.3  | mΩ   |
|   | R <sub>DS(on)2</sub> | V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 42 A |      | 4.9  | 6.5  | mΩ   |
| Input Capacitance                                   | C <sub>iss</sub>     | V <sub>DS</sub> = 10 V                         |      | 5500 |      | pF   |
| Output Capacitance                                  | C <sub>oss</sub>     | V <sub>GS</sub> = 0 V                          |      | 1050 |      | pF   |
| Reverse Transfer Capacitance                        | C <sub>rss</sub>     | f = 1 MHz                                      |      | 350  |      | pF   |
| Turn-on Delay Time                                  | t <sub>d(on)</sub>   | V <sub>DD</sub> = 30 V, I <sub>D</sub> = 42 A  |      | 19   |      | ns   |
| Rise Time   | t <sub>r</sub>       | V <sub>GS</sub> = 10 V                         |      | 13   |      | ns   |
| Turn-off Delay Time                                 | t <sub>d(off)</sub>  | R <sub>G</sub> = 0 Ω                           |      | 91   |      | ns   |
| Fall Time   | t <sub>f</sub>       |  |      | 10   |      | ns   |
| Total Gate Charge                                   | Q <sub>G</sub>       | V <sub>DD</sub> = 48 V                         |      | 96   |      | nC   |
| Gate to Source Charge                               | Q <sub>GS</sub>      | V <sub>GS</sub> = 10 V                         |      | 18   |      | nC   |
| Gate to Drain Charge                                | Q <sub>GD</sub>      | I <sub>D</sub> = 84 A                          |      | 23.5 |      | nC   |
| Body Diode Forward Voltage <sup>Note</sup>          | V <sub>F(S-D)</sub>  | I <sub>F</sub> = 84 A, V <sub>GS</sub> = 0 V   |      | 0.92 | 1.5  | V    |
| Reverse Recovery Time                               | t <sub>rr</sub>      | I <sub>F</sub> = 84 A, V <sub>GS</sub> = 0 V   |      | 49   |      | ns   |
| Reverse Recovery Charge                             | Q <sub>rr</sub>      | di/dt = 100 A/μs                               |      | 70   |      | nC   |

**Note** Pulsed

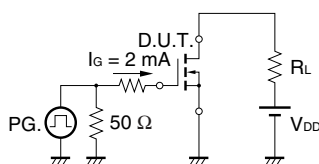
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



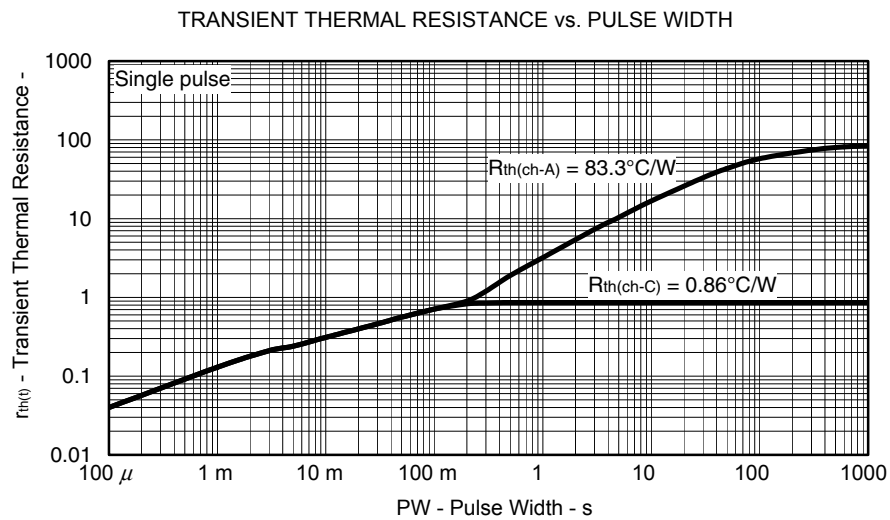
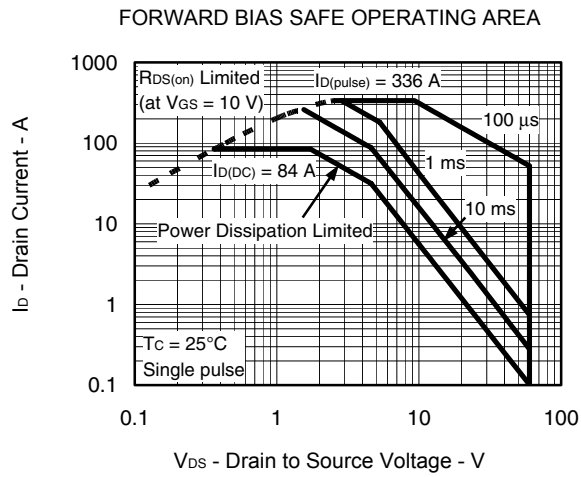
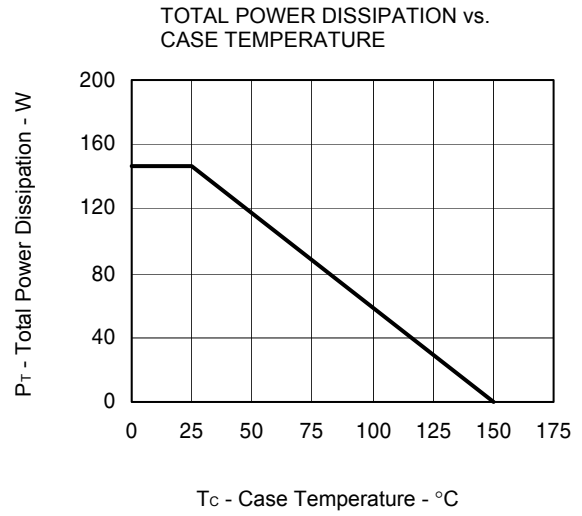
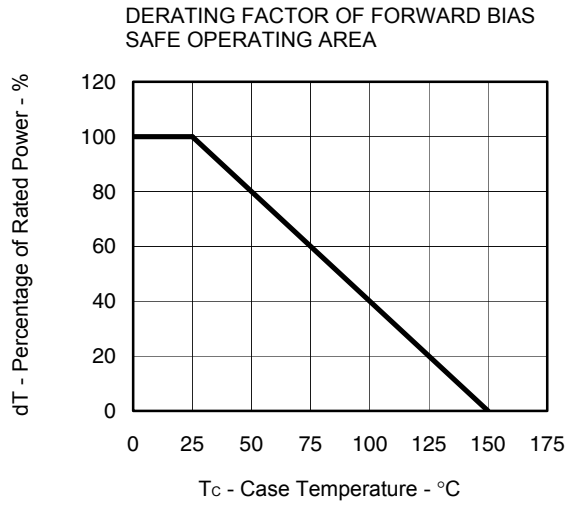
**TEST CIRCUIT 2 SWITCHING TIME**



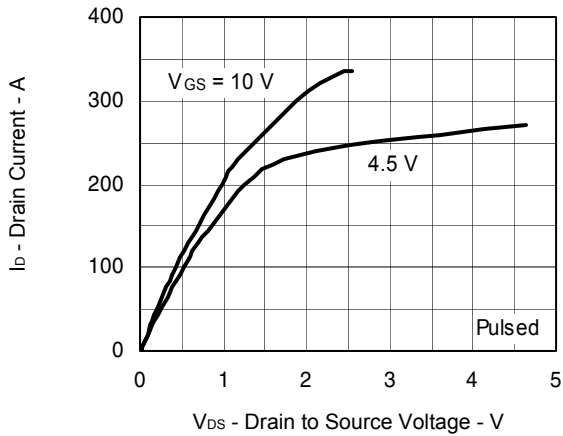
**TEST CIRCUIT 3 GATE CHARGE**



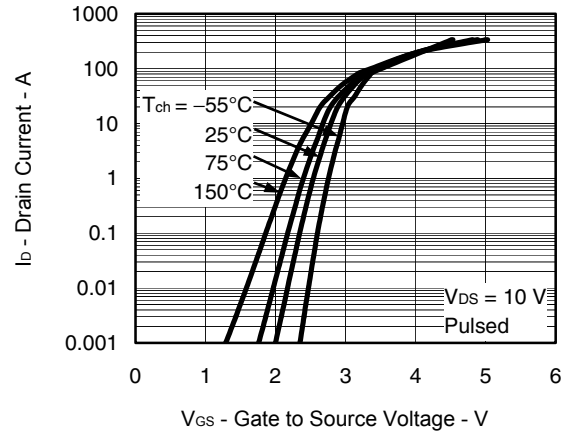
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



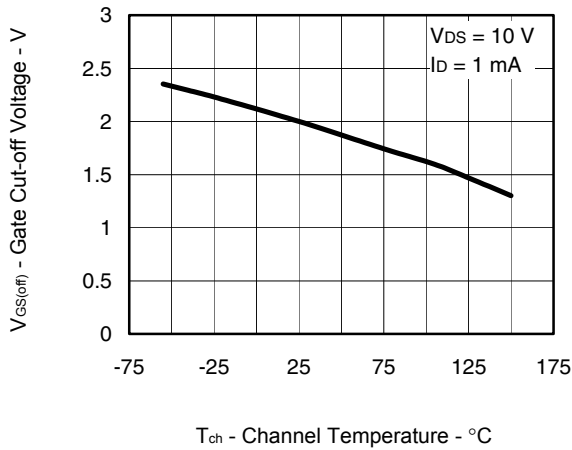
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



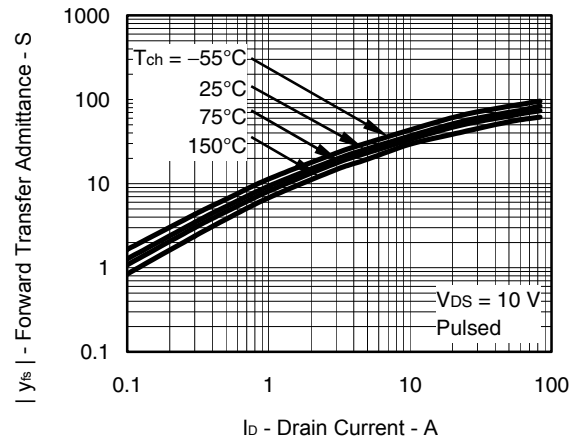
FORWARD TRANSFER CHARACTERISTICS



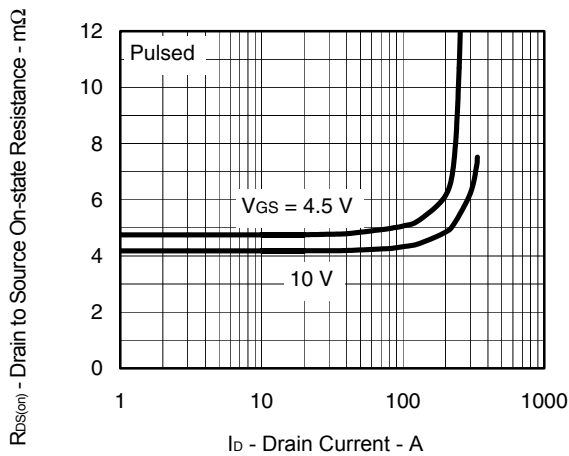
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



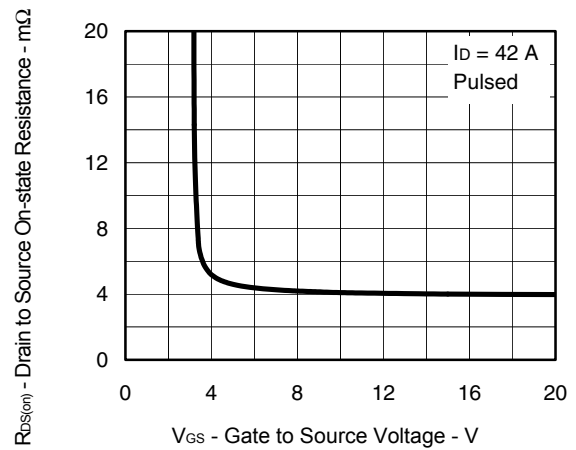
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



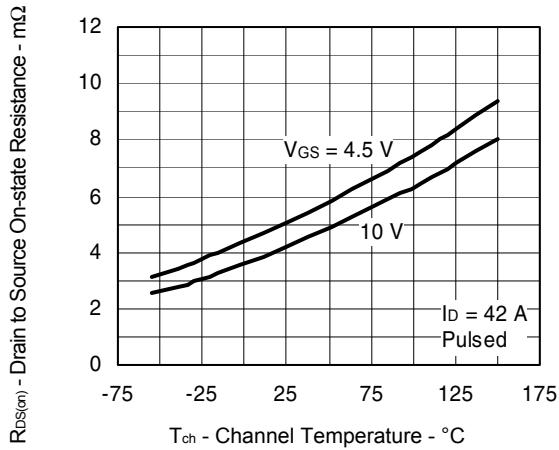
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



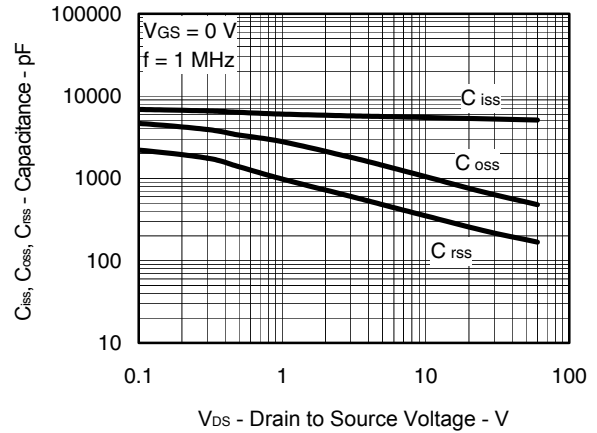
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



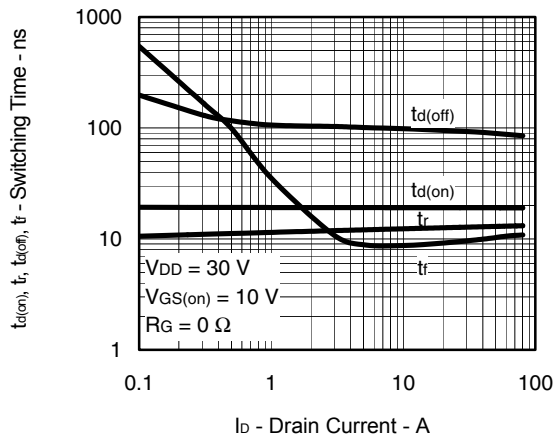
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



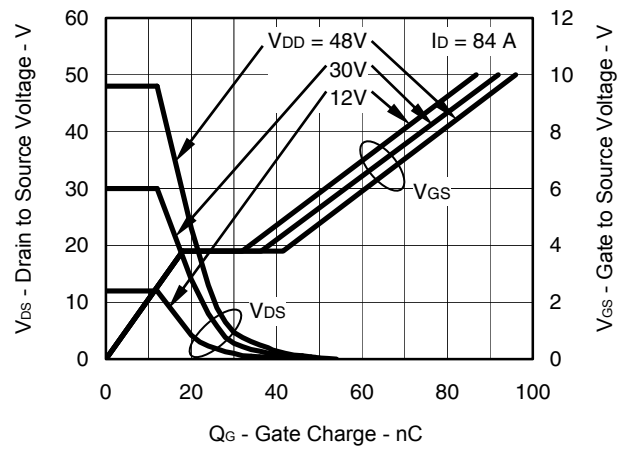
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



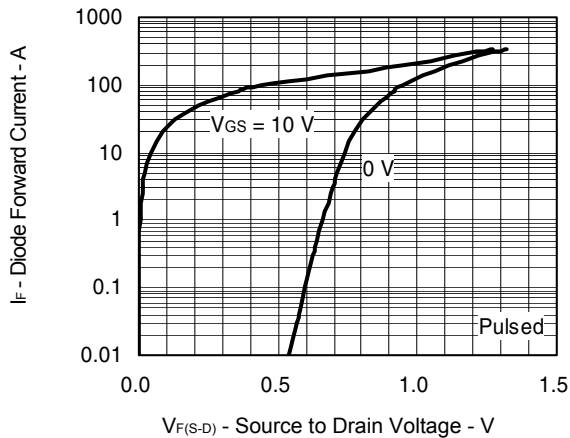
SWITCHING CHARACTERISTICS



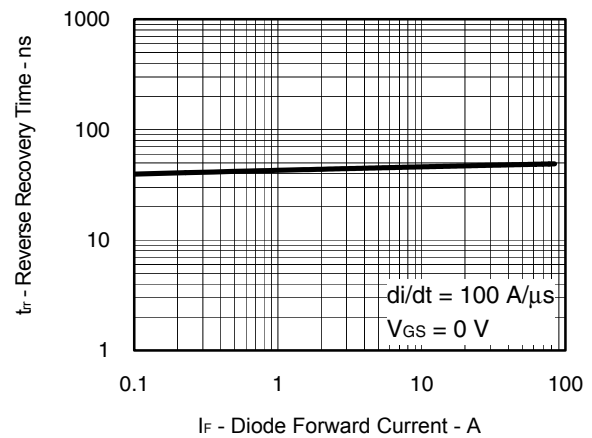
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



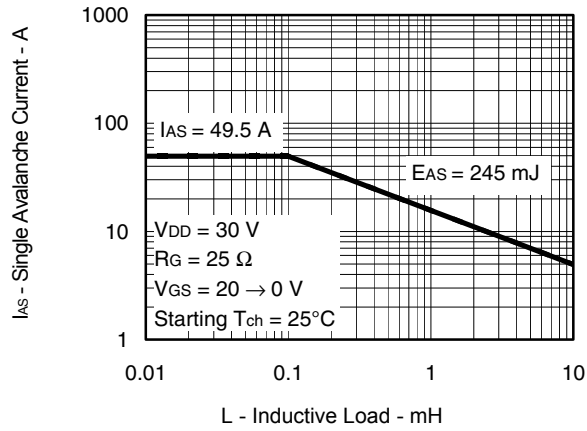
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



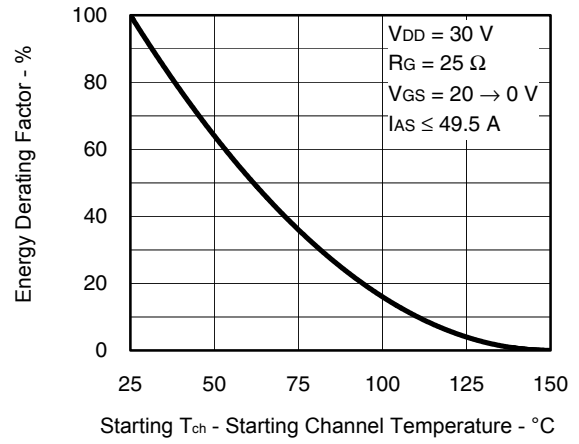
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



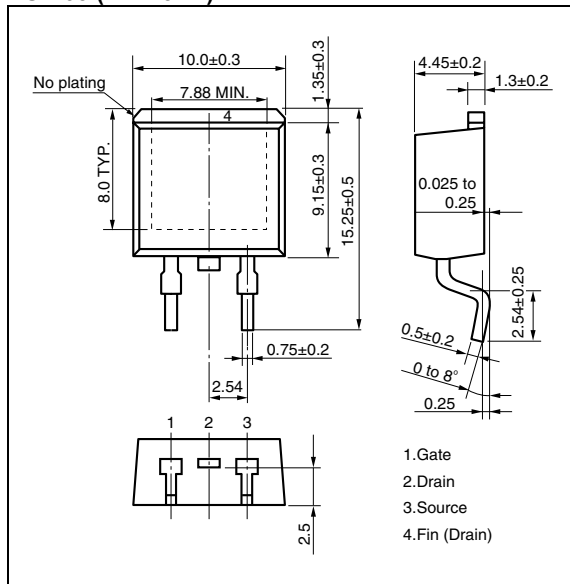
SINGLE AVALANCHE ENERGY DERATING FACTOR



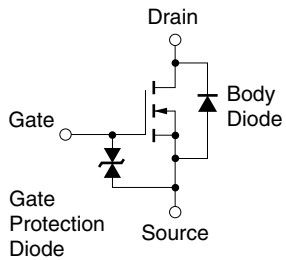


PACKAGE DRAWING (Unit: mm)

TO-263 (MP-25ZK)



EQUIVALENT CIRCUIT



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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